# UT54ACS08/UT54ACTS08

**Quadruple 2-Input AND Gates** 

January, 2018

**Datasheet** 

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#### **FEATURES**

- □ 0.6µ CRH CMOS
  - Latchup immune
- ☐ High speed
- ☐ Low power consumption
- ☐ Single 5 volt supply
- ☐ Available QML Q or V processes
- ☐ 14-lead flatpack
- ☐ UT54ACS08 SMD 5962-96518
- ☐ UT54ACTS08 SMD 5962-96519

#### DESCRIPTION

The UT54ACS08 and the UT54ACTS08 are quadruple two-input AND gates. The circuits perform the Boolean functions  $Y = A \cdot B$  or  $Y = \overline{\overline{A} + \overline{B}}$  in positive logic.

The devices are characterized over full military temperature range of -55°C to +125°C.

#### **FUNCTION TABLE**

INPUT		OUTPUT
Α	В	Υ
Н	Н	Н
L	X	L
Х	L	L

### LOGIC SYMBOL

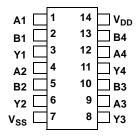
	(4)		
<b>A</b> 1	(1)	&	(3)
	(2)		( <del>)</del> Y1
В1			
A2	( <u>4)</u>		(6)
	<u>(5)</u>		(0) Y2
B2	<u> </u>		
	(9)		(8)
A3	(40)		( <del>0)</del> Y3
R3	(10)		
B3 A4	(12)		(44)
Α4			(11) Y4
R4	( <u>13)</u>		

#### Note:

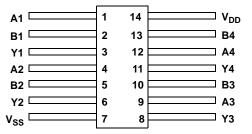
1. Logic symbol in accordance with ANSI/IEEE standard 91-1984 and IEC Publication 617-12.

#### **PINOUTS**

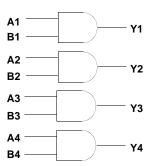




14-Pin Flatpack Top View



#### LOGIC DIAGRAM



### OPERATIONAL ENVIRONMENT<sup>1</sup>

PARAMETER	LIMIT	UNITS
Total Dose	500K	rads(Si)
SEU Threshold <sup>2</sup>	80	MeV-cm <sup>2</sup> /mg
SEL Threshold	120	MeV-cm <sup>2</sup> /mg
Neutron Fluence	1.0E14	n/cm <sup>2</sup>

- Logic will not latchup during radiation exposure within the limits defined in the table.
   Device storage elements are immune to SEU affects.

#### ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	LIMIT	UNITS
$V_{\mathrm{DD}}$	Supply voltage	-0.3 to 7.0	V
V <sub>I/O</sub>	Voltage any pin	$3$ to $V_{DD} + .3$	V
$T_{STG}$	Storage Temperature range	-65 to +150	°C
$T_{J}$	Maximum junction temperature	+175	°C
$T_{LS}$	Lead temperature (soldering 5 seconds)	+300	°C
$\Theta_{ m JC}$	Thermal resistance junction to case	15.5 (ACS) 15.0 (ACTS)	°C/W
$I_{\mathbf{I}}$	DC input current	±10	mA
$P_{D}$	Maximum power dissipation	1	W

#### RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMIT	UNITS
V <sub>DD</sub>	Supply voltage	4.5 to 5.5	V
V <sub>IN</sub>	Input voltage any pin	0 to V <sub>DD</sub>	V
$T_{\mathrm{C}}$	Temperature range	-55 to + 125	°C

Note:
1. Stresses outside the listed absolute maximum ratings may cause permanent damage to the device. This is a stress rating only, functional operation of the device at these or any other conditions beyond limits indicated in the operational sections is not recommended. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## DC ELECTRICAL CHARACTERISTICS 7

 $(V_{DD} = 5.0V \pm 10\%; V_{SS} = 0V^6, -55^{\circ}C < T_C < +125^{\circ}C);$  Unless otherwise noted, Tc is per the temperature range ordered.

SYMBOL	PA	RAMETER	CONDITION	MIN	MAX	UNIT
V <sub>IL</sub>	Low-level input ACTS ACS	voltage <sup>1</sup>			0.8 .3V <sub>DD</sub>	V
V <sub>IH</sub>	High-level input ACTS ACS	voltage <sup>1</sup>		.5V <sub>DD</sub> .7V <sub>DD</sub>		V
I <sub>IN</sub>	Input leakage cu ACTS/ACS	rrent	$V_{IN} = V_{DD}$ or $V_{SS}$	-1	1	μΑ
V <sub>OL</sub>	Low-level outpu ACTS ACS	t voltage <sup>3</sup>	$I_{OL} = 8.0 \text{mA}$ $I_{OL} = 100 \mu \text{A}$		0.40 0.25	V
V <sub>OH</sub>	High-level outpu ACTS ACS	it voltage <sup>3</sup>	$I_{OH} = -8.0 \text{mA}$ $I_{OH} = -100 \mu \text{A}$	.7V <sub>DD</sub> V <sub>DD</sub> - 0.25		V
I <sub>OS</sub>	Short-circuit out ACTS/ACS	put current <sup>2</sup> , <sup>4</sup>	$V_O = V_{DD}$ and $V_{SS}$	-200	200	mA
I <sub>OL</sub>	Output current <sup>10</sup> (Sink)		$V_{IN} = V_{DD}$ or $V_{SS}$ $V_{OL} = 0.4V$	8		mA
I <sub>OH</sub>	Output current <sup>1(</sup> (Source)	,	$V_{IN} = V_{DD}$ or $V_{SS}$ $V_{OH} = V_{DD} - 0.4V$	-8		mA
P <sub>total</sub>	Power dissipation	n 2, 8, 9	$C_L = 50pF$		1.8	mW/ MHz
I <sub>DDQ</sub>	Quiescent Supply Current	Pre-Rad Post-Rad Device Type 01	$V_{IN} = V_{DD} \text{ or } V_{SS}$ $V_{DD} = V_{DD} MAX$		50	μΑ
$\Delta I_{ m DDQ}$	Quiescent Suppl ACTS	y Current Delta	For input under test $V_{IN} = V_{DD} - 2.1V$ For all other inputs $V_{IN} = V_{DD} \text{ or } V_{SS}$ $V_{DD} = 5.5V$		1.6	mA
C <sub>IN</sub>	Input capacitanc	e <sup>5</sup>	f = 1MHz @ 0V		15	pF
C <sub>OUT</sub>	Output capacitar	nce <sup>5</sup>	f = 1MHz @ 0V		15	pF

#### **Notes:**

<sup>1.</sup> Functional tests are conducted in accordance with MIL-STD-883 with the following input test conditions:  $V_{IH} = V_{IH}(min) + 20\%$ , -0%;  $V_{IL} = V_{IL}(max) + 0\%$ , -50%, as specified herein, for TTL, CMOS, or Schmitt compatible inputs. Devices may be tested using any input voltage within the above specified range, but are guaranteed to  $V_{IH}(min)$  and  $V_{IL}(max)$ .

<sup>2.</sup> Supplied as a design limit but not guaranteed or tested.

<sup>3.</sup> Per MIL-PRF-38535, for current density  $\leq$  5.0E5 amps/cm<sup>2</sup>, the maximum product of load capacitance (per output buffer) times frequency should not exceed 3,765 pF/MHz.

<sup>4.</sup> Not more than one output may be shorted at a time for maximum duration of one second.

- 5. Capacitance measured for initial qualification and when design changes may affect the value. Capacitance is measured between the designated terminal and VSS at frequency of 1MHz and a signal amplitude of 50 mV rms maximum.
- 6. Maximum allowable relative shift equals 50mV.
  7. Device type 01 is only offered with a TID tolerance guarantee of 1E5 rads(Si), 3E5 rads(Si), and 5E5 rads(Si), and is tested in accordance with MIL-STD-883 Test Method 1019 Condition A.
- 8. Power does not include power contribution of any TTL output sink current.
  9. Power dissipation specified per switching output.
- 10. This value is guaranteed based on characterization data, but not tested.

## AC ELECTRICAL CHARACTERISTICS $^{\rm 2}$

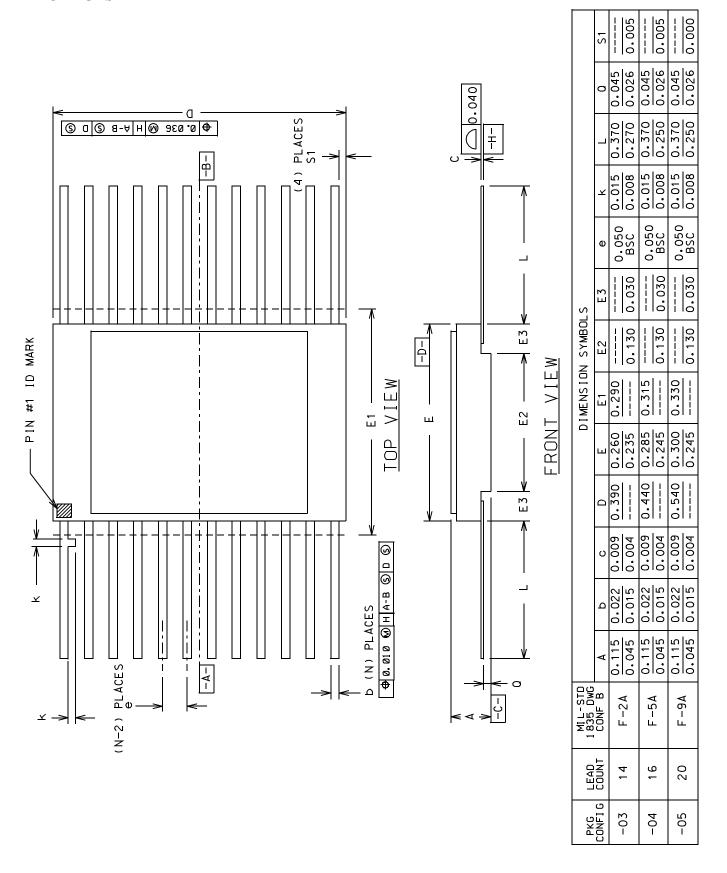
 $(V_{DD} = 5.0V \pm 10\%; \ V_{SS} = \ 0V^{-1}, \ -55^{\circ}C < T_{C} < +125^{\circ}C); \ Unless \ otherwise \ noted, \ Tc \ is \ per \ the \ temperature \ range \ ordered.$ 

SYMBOL	PARAMETER	MINIMUM	MAXIMUM	UNIT
t <sub>PHL</sub>	Input to Yn	1	13	ns
t <sub>PLH</sub>	Input to Yn	1	10	ns

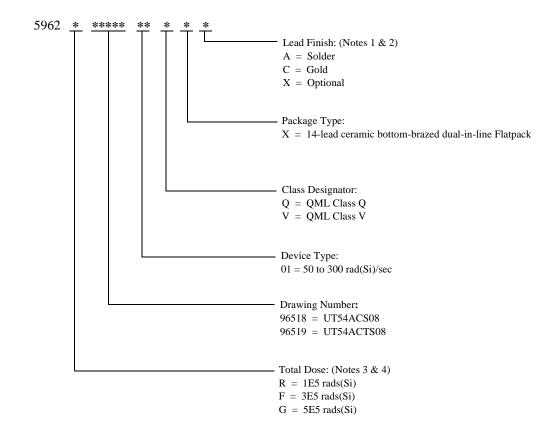
#### **Notes:**

- Maximum allowable relative shift equals 50mV.
   Device type 01 is only offered with a TID tolerance guarantee of 1E5 rads(Si), 3E5 rads(Si), and 5E5 rads(Si), and is tested in accordance with MIL-STD-883 Test Method 1019 Condition A.

### **PACKAGES**



#### UT54ACS08/UT54ACTS08: SMD



#### Notes:

- 1. Lead finish (A,C, or X) must be specified.
- 2. If an "X" is specified when ordering, part marking will match the lead finish and will be either "A" (solder) or "C" (gold).
- 3. Total dose radiation must be specified when ordering. QML Q and QML V not available without radiation hardening. For prototype inquiries, contact factory.
- 4. Device type 01 is only offered with a TID tolerance guarantee of 1E5 rads(Si), 3E5 rads(Si), and 5E5 rads(Si), and is tested in accordance with MIL-STD-883 Test Method 1019 Condition A.

## Aeroflex Colorado Springs - Datasheet Definition

Advanced Datasheet - Product In Development

Preliminary Datasheet - Shipping Prototype

Datasheet - Shipping QML & Reduced Hi-Rel

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### DATA SHEET REVISION HISTORY

Revision Date	Description of Change	
10-17	Page 3 edited IDDQ Applied new Cobham Data Sheet template to the document.	
1-18	Updates to reflect current SMD	RT